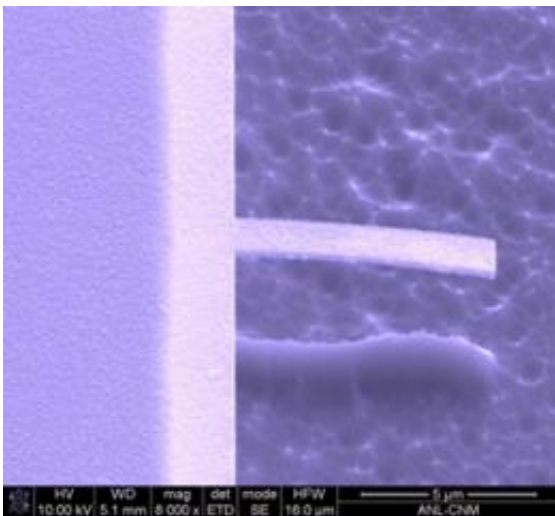


# Highlight: Mechanical energy dissipation in ultrananocrystalline diamond microresonators

August 12 2009

---



SEM micrograph of fabricated UNCD microresonator

Researchers in the Nanofabrication and Devices group at the Argonne National Laboratory, in collaboration with the University of Pennsylvania, Advanced Diamond Technologies Inc., and Innovative Micro Technology, have discovered that defects at the grain boundary in ultrananocrystalline diamond (UNCD) hold primary responsibility for the fundamental mechanism of energy dissipation.

Because of a high Young's modulus and high sound propagation velocity, UNCD materials hold potential for fabricating high-frequency

microelectromechanical (MEMS) resonators.

However, their mechanical dissipation at high frequency, which is important for developing high-frequency resonator applications, is not well understood. Dissipation in UNCD cantilevers was determined by using ring-down measurement under ultrahigh-vacuum conditions, and the quality factor measured in the range of 5000-16000 at kHz resonance frequencies.

These studies reveal that dissipation in UNCD films is mainly due to the presence of defects such as nondiamond-carbon bonding at grain boundaries.

More information: V. P. Adiga, A. V. Sumant, S. Suresh, C. Gudeman, O. Auciello, J. A. Carlisle, R. W. Carpick, "Mechanical stiffness and dissipation in ultrananocrystalline diamond microresonators," *Phys. Rev. B*, 79, 245403 (2009)

Provided by Argonne National Laboratory ([news](#) : [web](#))

Citation: Highlight: Mechanical energy dissipation in ultrananocrystalline diamond microresonators (2009, August 12) retrieved 27 April 2024 from <https://phys.org/news/2009-08-highlight-mechanical-energy-dissipation-ultrananocrystalline.html>

<p>This document is subject to copyright. Apart from any fair dealing for the purpose of private study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.</p>
--